

IPB110N20N3LFATMA1

IPB110N20N3LFATMA1 Information

Heisener.com	 IPB110N20N3LFATMA1 Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single MOSFET N-CH 200 D2PAK-3 - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPB110N20N3LFATMA1 Specifications

Manufacturer Part Number	IPB110N20N3LFATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	-
Series	*
FET Type	-
Technology	-
Drain to Source Voltage (Vdss)	-
Current - Continuous Drain (Id) @ 25°C	-
Drive Voltage (Max Rds On, Min Rds On)	-
Vgs(th) (Max) @ Id	-
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	-
Vgs (Max)	-
FET Feature	-
Power Dissipation (Max)	-
Rds On (Max) @ Id, Vgs	-
Operating Temperature	-
Mounting Type	-
Supplier Device Package	-
Package / Case	-
	Report errors?

IPB110N20N3LFATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

IPB110N20N3LFATMA1 Payment Methods



IPB110N20N3LFATMA1 Shipping Methods



If you have any question about IPB110N20N3LFATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com